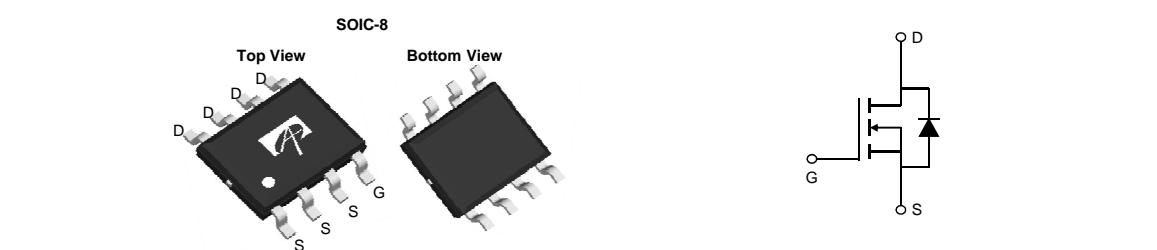


General Description	Product Summary
<ul style="list-style-type: none"> Trench Power AlphaMOS (αMOS MV) technology Low $R_{DS(ON)}$ Low Gate Charge Optimized for fast-switching applications RoHS and Halogen-Free Compliant 	V_{DS} 100V I_D (at $V_{GS}=10V$) 8A $R_{DS(ON)}$ (at $V_{GS}=10V$) $< 23m\Omega$ $R_{DS(ON)}$ (at $V_{GS}=4.5V$) $< 33m\Omega$ 100% UIS Tested 100% R_g Tested
Applications <ul style="list-style-type: none"> Synchronous Rectification in DC/DC and AC/DC Converters Isolated DC/DC Converters in Telecom and Industrial 	



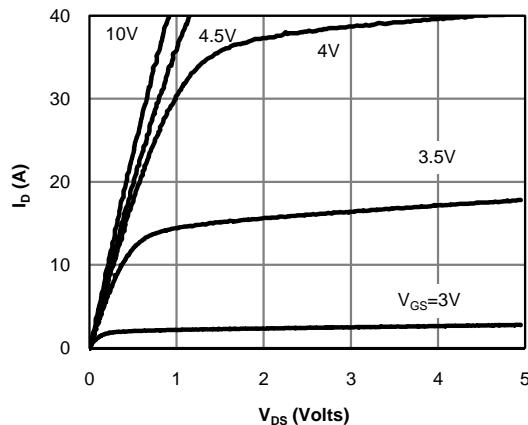
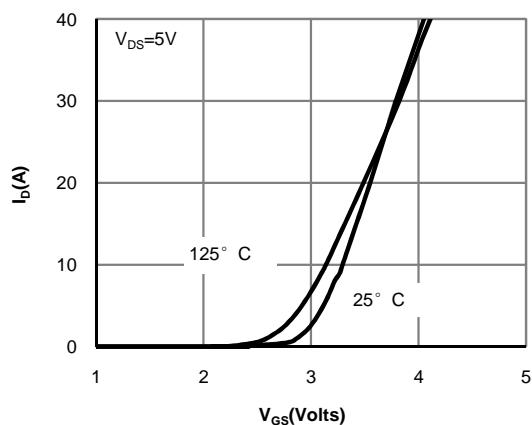
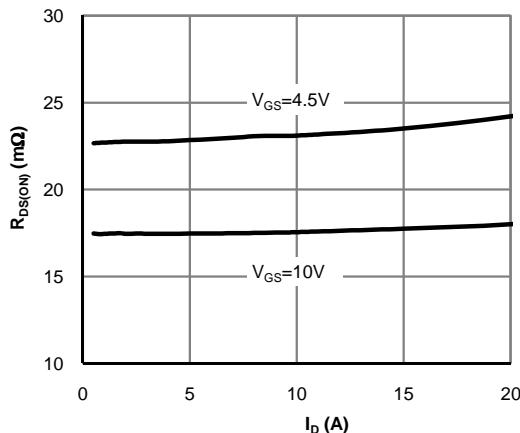
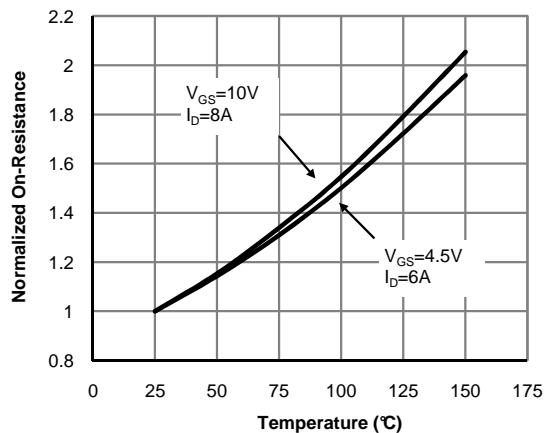
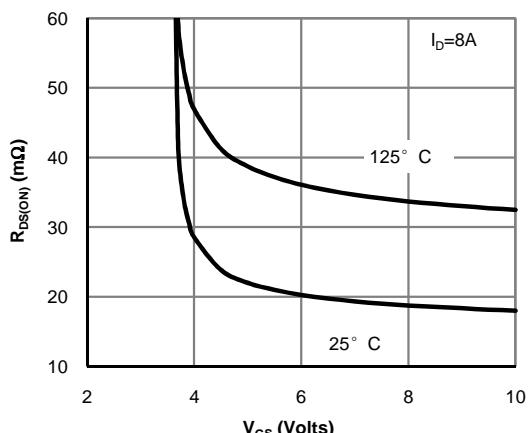
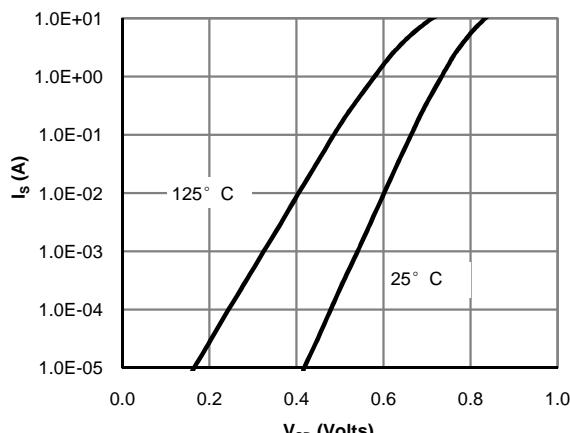
Orderable Part Number	Package Type	Form	Minimum Order Quantity
AO4292	SO-8	Tape & Reel	3000

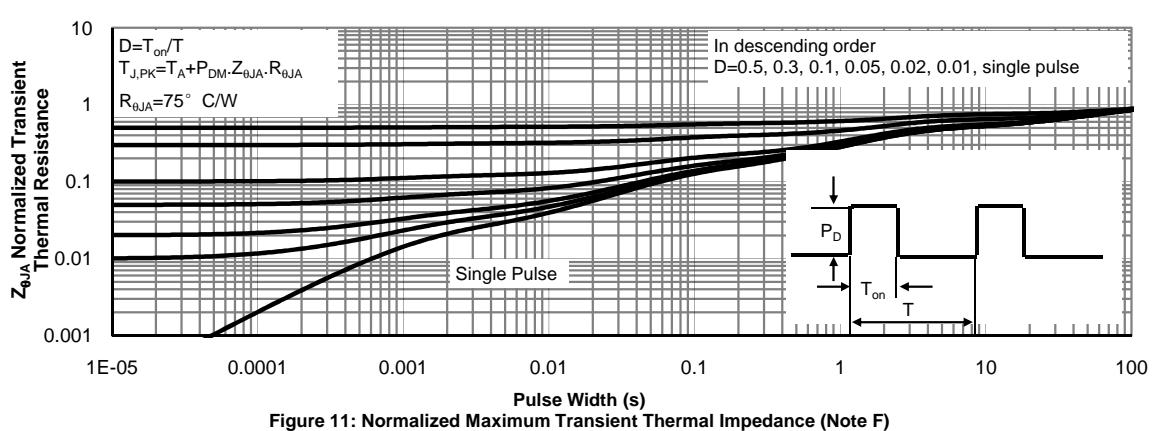
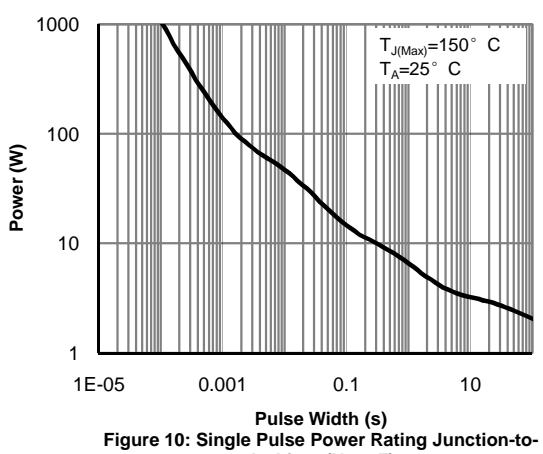
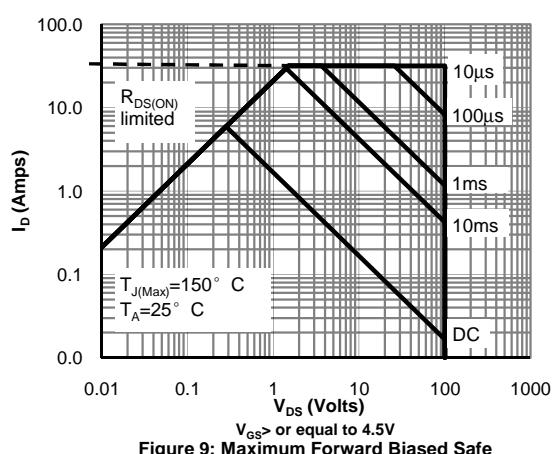
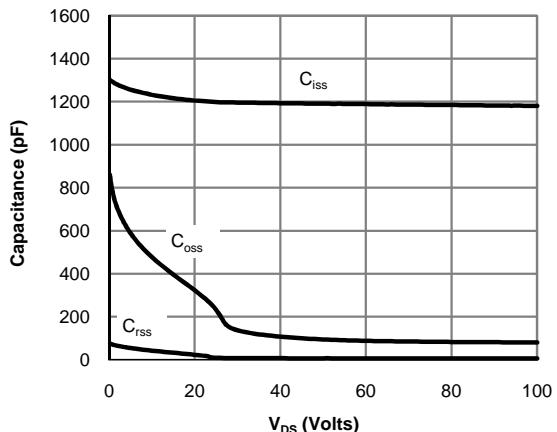
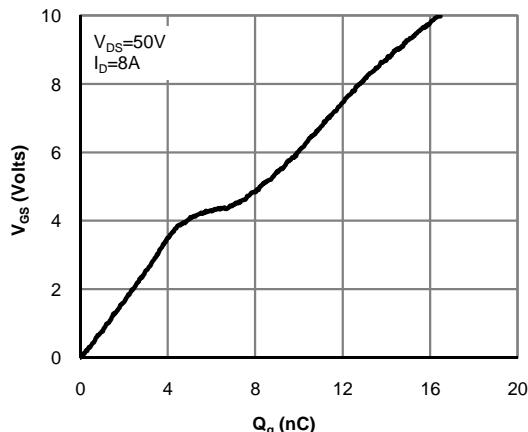
Absolute Maximum Ratings $T_A=25^\circ C$ unless otherwise noted

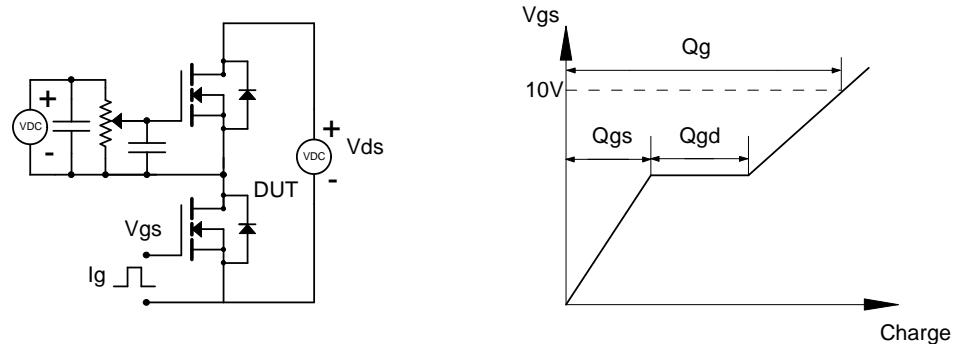
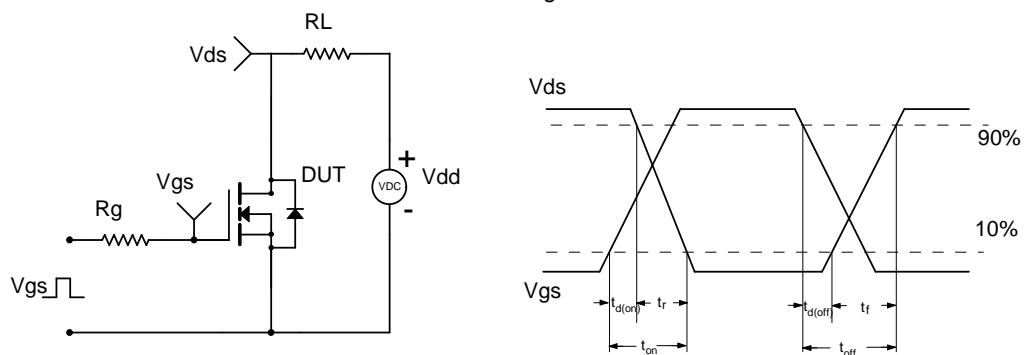
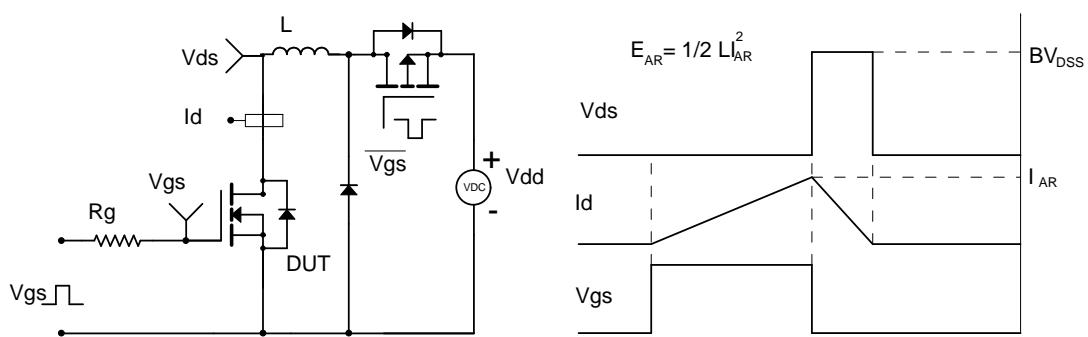
Parameter	Symbol	Maximum	Units
Drain-Source Voltage	V_{DS}	100	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current ^A $T_A=25^\circ C$	I_D	8	A
Continuous Drain Current ^A $T_A=70^\circ C$		6.2	
Pulsed Drain Current ^C	I_{DM}	32	A
Avalanche Current ^C	I_{AS}	15	A
Avalanche energy ^C $L=0.1mH$	E_{AS}	11	mJ
V_{DS} Spike	$10\mu s$	V_{SPIKE}	V
Power Dissipation ^B $T_A=25^\circ C$	P_D	3.1	W
		2.0	
Junction and Storage Temperature Range	T_J, T_{STG}	-55 to 150	°C

Thermal Characteristics

Parameter	Symbol	Typ	Max	Units
Maximum Junction-to-Ambient ^A $t \leq 10s$	$R_{\theta JA}$	31	40	°C/W
Maximum Junction-to-Ambient ^{A,D} Steady-State		59	75	°C/W
Maximum Junction-to-Lead Steady-State	$R_{\theta JL}$	16	24	°C/W

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

Figure 1: On-Region Characteristics (Note E)

Figure 2: Transfer Characteristics (Note E)

Figure 3: On-Resistance vs. Drain Current and Gate Voltage (Note E)

Figure 4: On-Resistance vs. Junction Temperature (Note E)

Figure 5: On-Resistance vs. Gate-Source Voltage (Note E)

Figure 6: Body-Diode Characteristics (Note E)

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS


Gate Charge Test Circuit & Waveform

Resistive Switching Test Circuit & Waveforms

Unclamped Inductive Switching (UIS) Test Circuit & Waveforms

Diode Recovery Test Circuit & Waveforms
